
**Cards and security devices for
personal identification — Contactless
proximity objects —**

**Part 2:
Radio frequency power and signal
interface**

**AMENDMENT 1: Dynamic power level
management**

*Cartes et dispositifs de sécurité pour l'identification personnelle —
Objets sans contact de proximité —*

Partie 2: Interface radiofréquence et des signaux de communication

AMENDEMENT 1: Gestion dynamique de niveau de puissance





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This document was prepared by Joint Technical Committee ISO/IEC JTC 1, *Information technology*, Subcommittee SC 17, *Cards and security devices for personal identification*.

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Part 2: Radio frequency power and signal interface

AMENDMENT 1: Dynamic power level management

Page 3, Clause 4

Add the following symbols:

- " H_{LP} minimum requested field strength"
- " $H_{step, max}$ PCD maximum field strength step increase or step decrease"

Page 6, 6.3

Replace the first paragraph with the following text:

"Within the manufacturer specified operating volumes (see 3.6),

- the PCD shall generate a field strength of at least H_{min} and not exceeding H_{max} under unmodulated conditions, see Table 1;
- the PCD may generate a field strength lower than H_{min} only in case the PICC allows a decrease in the PCD field strength as specified in other parts of ISO/IEC 14443 and only for the processing of that PICC.

The PCD field strength step increase and step decrease shall be less than $H_{step, max} = 3$ dB (a factor of $\sim 1,4$) and may be achieved by any wave shape, e.g., by several increments.

WARNING — The PCD design shall take into account the field strength variation caused by the two different loading effects used in the associated test."

Add the following paragraphs just before Table 2:

"Additionally, if the PICC allows a decrease in the PCD field strength down to a value less than H_{min} , then the PICC shall be able to operate as intended continuously between that value and H_{min} defined for its class, see Table 2.

The minimum requested field strength H_{LP} is $H_{step, max}$ below the lowest field strength at which the PICC indicates $PLI_{ATQ} = (11)b$ or $PLI_{CID} = (10)b$ or $(11)b$ (see ISO/IEC 14443-3:2018/Amd 1 and ISO/IEC 14443-4:2018/Amd 1)."

Page 24, 8.2.2.2, Table 22

Replace " $22/H^{0.5}$ " with " $\text{Min}(18 ; 22/H^{0.5})$ " for $V_{\text{LMA, min, PICC}}$ requirement (first column) for "Class 1" PICC (first row).

Page 34, 9.1.2

Add the following paragraph just before Figure 22:

"Additionally, if the PICC allows a decrease in the PCD field strength down to a value less than H_{min} , then the PICC shall be able to receive for any bit combination a modulation waveform with a modulation index, m , greater than 8 % and less than 15 % for bit rates of $f_c/128$, $f_c/64$, $f_c/32$ and $f_c/16$ between that value and H_{min} defined for its class, see Table 2."

Page 43, 10.2

Add the following paragraph just after NOTE 1 (i.e. before the paragraph starting with "During this low EMD time"):

"Additionally, if the PICC allows a decrease in the PCD field strength down to a value less than H_{min} , then for all PICC classes, the EMD level before PICC data transmission shall be less than $V_{\text{E, PICC}}$ defined for H_{min} that is $2/3 + 3/H_{\text{min}}^2$ [mV (peak)]."